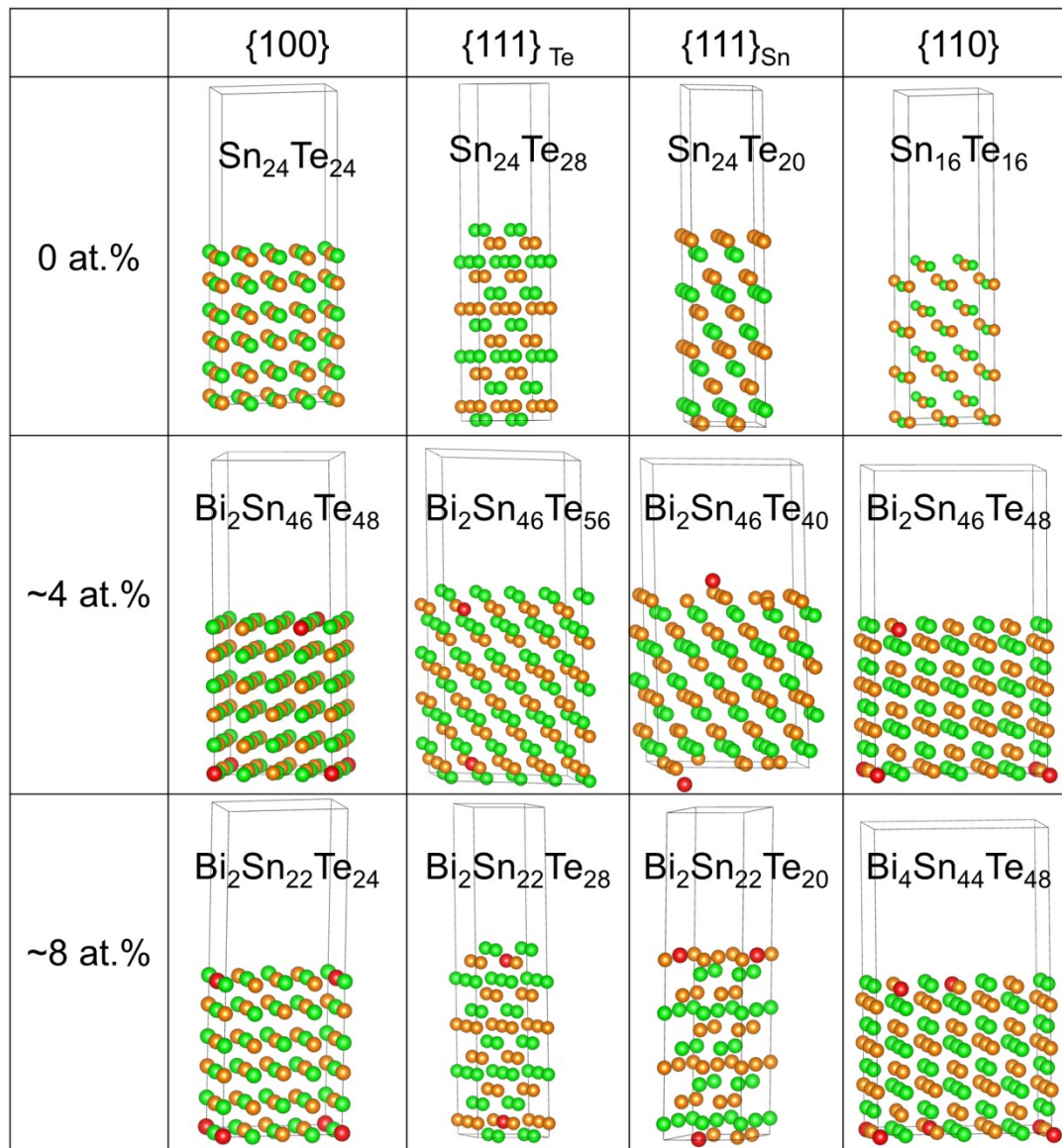


# Supporting Information for “Surface-Energy Engineered Bi-doped SnTe Nanoribbons with Weak Antilocalization Effect and Linear Magnetoresistance”

*Yi-Chao Zou,<sup>a</sup> Zhi-Gang Chen,<sup>a,b,\*</sup> Fantai Kong,<sup>c</sup> Enze Zhang,<sup>d</sup> John Drennan,<sup>e</sup> Kyeongjae Cho,<sup>c</sup> Faxian Xiu<sup>d</sup> and Jin Zou<sup>a, e,\*</sup>*

- a. Materials Engineering, University of Queensland, Brisbane, QLD 4072, Australia
- b. Centre for Future Materials, University of Southern Queensland, Springfield, QLD 4300, Australia
- c. Department of Materials Science & Engineering, The University of Texas at Dallas, Richardson, TX 75080, USA
- d. Key Laboratory of Surface Physics and Department of Physics, and Collaborative Innovation Center of Advanced Microstructures, Fudan University, Shanghai 200433, China
- e. Centre for Microscopy and Microanalysis, University of Queensland, Brisbane, QLD 4072, Australia

### S1. Supercells for Surface-Energy Calculations



**Figure S1.** Configurations of the adopted atomic models (after structural relaxation) for calculation of SnTe surface energies with different Bi doping concentrations.